

2000V Silicon Carbide Schottky Diode

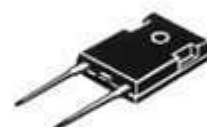
DESCRIPTION :

- High voltage
- Low forward voltage
- High Speed Switching
- Positive temperature Coefficient
- Easy to paralleling
- RoHS Compliant

V_{RRM}	2000V
I_F	10A (TC=157°C)
Q_C	137nC

TYPICAL APPLICATIONS :

- Switch mode power supplies
- Solar inverters
- Power factor correction



TO-247AC

MAXIMUM RATINGS (at $T_C = 25^\circ\text{C}$, unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V_{RRM}	2000	V
Continuous Forward Current	$T_C=25^\circ\text{C}$ $T_C=135^\circ\text{C}$ $T_C=1527$	I_F	46 23 10	A
Non-Repetitive Forward Surge Current	$T_C=25^\circ\text{C}$, $t_P=10\text{ms}$, Half sine pulse $T_C=110^\circ\text{C}$, $t_P=10\text{ms}$, Half sine pulse	I_{FSM}	80 60	A
Repetitive Peak Forward Surge Current	$T_C=25^\circ\text{C}$, $t_P=10\text{ms}$, Half sine pulse	I_{FRM}	72	A
i^2t value	$T_C=25^\circ\text{C}$, $t_P=10\text{ms}$ $T_C=110^\circ\text{C}$, $t_P=10\text{ms}$	$\int i^2 dt$	32 18	A^2S
Power dissipation	$T_C=25^\circ\text{C}$ $T_C=110^\circ\text{C}$ $T_C=150^\circ\text{C}$	P_{tot}	384 166 64	W
Operation Junction temperature		T_J	-55~+175	$^\circ\text{C}$
Storage temperature		T_{STG}	-55~+175	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Condition	Symbol	Typical	Unit
Thermal resistance, junction - case		$R_{th(j-c)}$	0.39	$^{\circ}\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS (at $T_c = 25^{\circ}\text{C}$, unless otherwise specified)

Characteristic	Symbol	Min.	Typ.	Max.	Unit
DC Blocking Voltage	V_{DC}	2000			V
Forward Voltage IF = 5A IF = 10A, $T_c = 25^{\circ}\text{C}$ IF = 10A, $T_c = 175^{\circ}\text{C}$	V_F		1.18 1.42 2.23	1.6	V
Reverse Current VR = 2000V, $T_c = 25^{\circ}\text{C}$ VR = 2000V, $T_c = 175^{\circ}\text{C}$	I_R		7 27	150	μA
Total Capacitive Charge VR = 1500V	Q_C		137		nC
Total capacitance VR = 1V, f = 1MHz VR = 800V, f = 1MHz VR = 1500V, f = 1MHz	C		960 67 65		pF
Capacitance Stored Energy VR = 1500 V	E_C		79		μJ

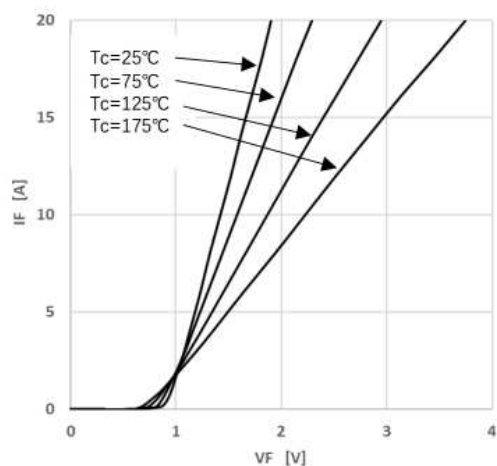


Figure 1. Forward characteristics

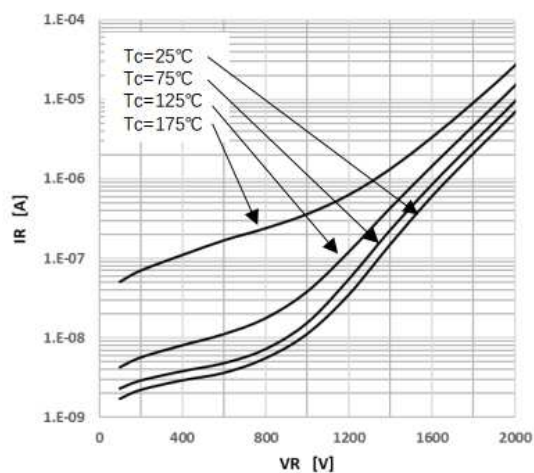


Figure 2. Reverse characteristics

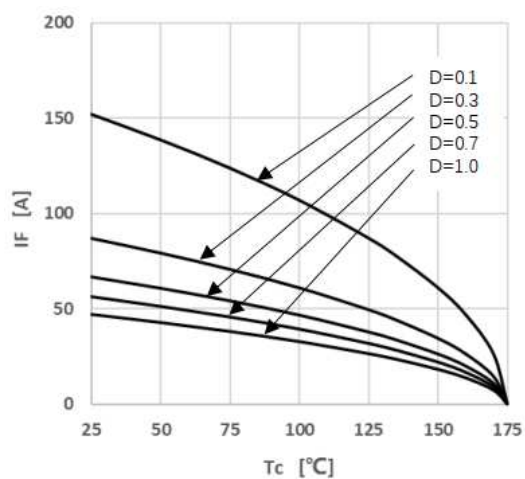


Figure 3. Peak Forward Current Derating

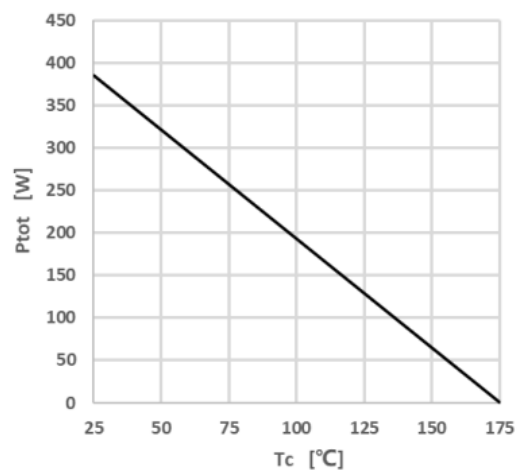


Figure 4. Power Dissipation

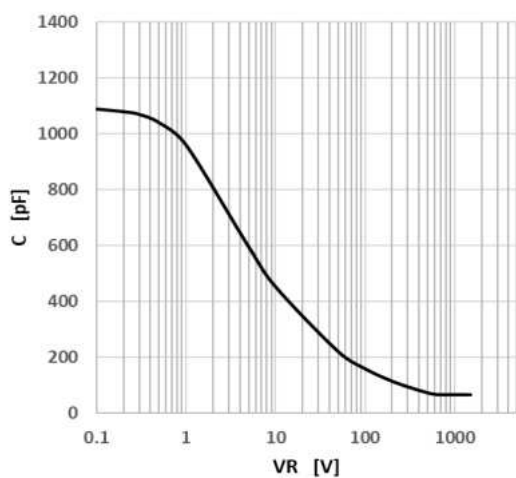


Figure 5. Capacitance vs. Reverse Voltage

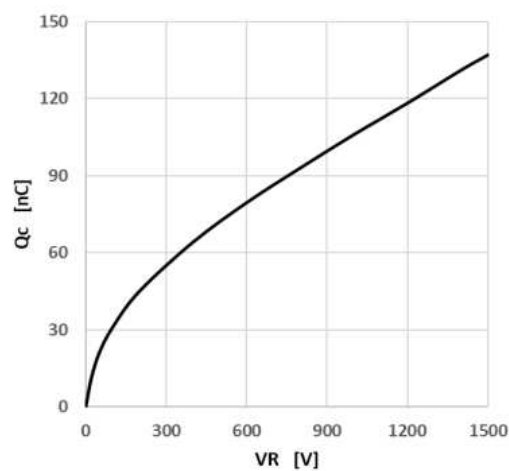


Figure 6. Capacitance Charge vs. Reverse Voltage

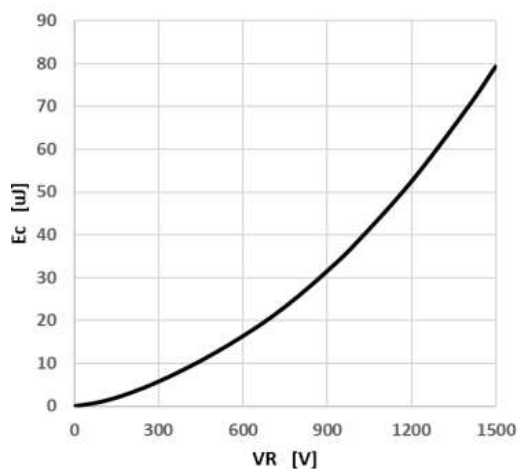


Figure 7. Capacitance Stored Energy

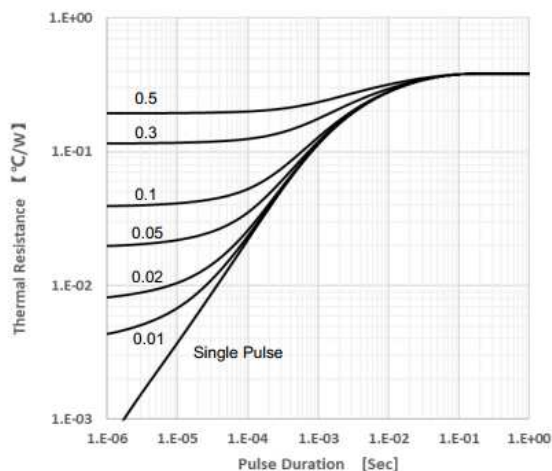
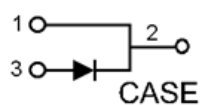
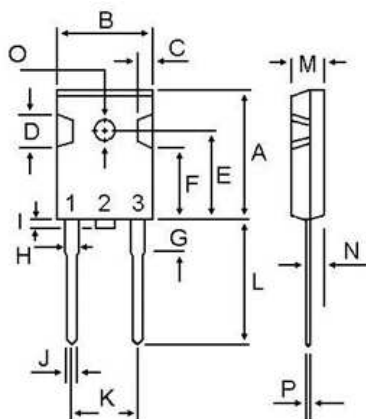


Figure 8. Transient Thermal Impedance

- Circuit diagram



- TO-247AC Package outlines : Dimensions in (mm)



DIM	MILLIMETERS	
	MIN	MAX
A	20.63	22.38
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.81	15.22
F	11.72	12.84
G	3.75	4.35
H	1.82	2.46
I	---	1.25
J	0.89	1.53
K	10.52	11.32
L	18.50	21.50
M	4.68	5.36
N	2.40	2.80
O	3.25	3.65
P	0.55	0.70

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